Diode Semiconductor Device - Page 1 of 1



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	ure Material:
Glass	
	I Length:
0.300 ir	
	al Length:
0.975 ir	
	I Diameter:
0.145 ir	
	on For Which Designed:
Zener o	
	ing Method:
Termin	
	es Provided:
	ically sealed case
Semico	onductor Material:
Silicon	
Voltage	e Rating In Volts Per Characteristic:
80.0 r	egulator voltage
Voltage	e Tolerance In Percent:
-5.0/+5	.0
Curren	t Rating Per Characteristic:
15.00 n	nilliamperes all primaries horsepower metric
Power	Rating Per Characteristic:
5.0 wat	ts small-signal input power, common-collector preset
Maxim	um Operating Tempurature Per Measurement Point:
175.0 d	legrees celsius ambient air
Termin	al Type And Quantity:
2 unins	ulated wire lead
Shelf L	.ife:
N/a	
Unit Of	f Measure:
Demilit	tarization:
No	
Fiig:	
A110a0)